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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/643,335	08/15/2003	Tung-Cheng Kuo	JCLA7850-D	3975
75	90 03/26/2004		EXAMINER	
J.C Patents			NGUYEN, DAO H	
Suite 250			, pm v p um	DADED MUNICIPA
4 Venture			ART UNIT	PAPER NUMBER
Irvine, CA 92	618		2818	
			DATE MAILED: 03/26/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

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	Application No.	Applicant(s)	
	10/643,335	KUO ET AL.	
Office Action Summary	Examiner	Art Unit	
	Dao H Nguyen	2818	
The MAILING DATE of this communication Period for Reply	appears on the cover sheet v	ith the correspondence address	5
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication - If the period for reply specified above is less than thirty (30) days, and a lift NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by standard the provided by the Office later than three months after the maximum adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may a n. a reply within the statutory minimum of the riod will apply and will expire SIX (6) MC latute, cause the application to become A	reply be timely filed irty (30) days will be considered timely. NTHS from the mailing date of this commun. BANDONED (35 U.S.C. § 133).	sication.
Status			
1) ☐ Responsive to communication(s) filed on 1 2a) ☐ This action is FINAL. 2b) ☐ 3 3) ☐ Since this application is in condition for all closed in accordance with the practice und	This action is non-final. owance except for formal ma	•	rits is
Disposition of Claims			
4) ☐ Claim(s) 1-8 is/are pending in the application 4a) Of the above claim(s) is/are with 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-8 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction are	drawn from consideration.		
Application Papers			
9)⊠ The specification is objected to by the Exam 10)⊠ The drawing(s) filed on 15 August 2003 is/a Applicant may not request that any objection to Replacement drawing sheet(s) including the co 11)□ The oath or declaration is objected to by the	are: a) \square accepted or b) \square of the drawing(s) be held in abeyon trection is required if the drawin	nnce. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR 1.	
Priority under 35 U.S.C. § 119			
12) △ Acknowledgment is made of a claim for force a) △ All b) ☐ Some * c) ☐ None of: 1. ☐ Certified copies of the priority docum 2. △ Certified copies of the priority docum 3. ☐ Copies of the certified copies of the application from the International Bu * See the attached detailed Office action for a	nents have been received. nents have been received in priority documents have bee reau (PCT Rule 17.2(a)).	Application No. <u>10/134,223</u> . n received in this National Stag	je
Attachment(s) 1) Notice of References Cited (PTO-892)	. 4) Interview	Summary (PTO-413)	
 Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SE Paper No(s)/Mail Date) Paper No	(s)/Mail Date Informal Patent Application (PTO-152)	

DETAILED ACTION

1. In response to the communications dated 08/15/2003, claims 1-8 are active in this application as a result of the cancellation of claims 9-19 in the Preliminary Amendment filed 08/15/2003.

Acknowledges

2. Receipt is acknowledged of the following items from the Applicant.

This application is a Divisional of the U.S. Application No. 10/134,223, filed 04/25/2002, now U.S. Patent No. 6,680,227.

Foreign Priority

3. Receipt is acknowledged of papers submitted under 35 U.S.C. 119(a)-(d), which papers have been placed of record in parent Application 10/134,223.

Specification

4. The specification is objected for the following reason: In the Abstract, line 2, in the phrase "the word line includes a metal layer a polysilicon line", a word –and—should

be inserted between "a metal layer" and "a polysilicon line" in order to be consistent with the description.

The specification has been checked to the extent necessary to determine the presence of possible minor errors. However, the applicant's cooperation is requested in correcting any errors of which applicant may become aware in the specification.

Claim Objections

5. Claim 1 is objected to because of the following reasons: in claim 1, line 2, the limitation "the word **lin**" should be changed to –the word line--. Appropriate correction is required.

Claim Rejections - 35 USC § 102

6. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless --

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 7. Claim(s) 1-3, and 5-8 is/are rejected under 35 U. S. C. § 102 (b) as being anticipated by U.S. Patent No. 5,497,345 to Cappelletti.

Regarding claim 1, Cappelletti discloses a non-volatile read only memory device, as shown in figure 3, comprising:

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a word line 7 formed over a substrate 2, wherein the word line includes a metal layer and a polysilicon line (col. 4, lines 9-18);

a trapping layer 21 located between the word line 7 and the substrate 2; and a polysilicon protection line 23 & 24 (extending from the word line 7 to the a grounded doped region 29) formed over the substrate 2, the protection line electrically connects the word line 7 and the grounded doped region 29 in the substrate 2, wherein a resistance of the polysilicon protection line is higher than that of the word line. See also column 4, line 53 to column 5, line 7.

Regarding claim 2, Cappelletti discloses the device wherein the resistance of the polysilicon protection line is higher than that of the polysilicon line of the word line. See column 4, line 53 to column 5, line 7.

Regarding claim 3, Cappelletti discloses the device wherein the polysilicon protection line is connected to the grounded doped region 29 through a contact. See figure 3.

Regarding claim 5, Cappelletti discloses the device wherein the metal layer includes tungsten silicide. See column 4, lines 9-18.

Regarding claim 6, Cappelletti discloses the device wherein the polysilicon protection line is located above an isolation region 20. See figure 3.

Regarding claim 7, Cappelletti discloses the device wherein the isolation region include a field oxide layer. See figure 3.

Regarding claim 8, Cappelletti discloses the device wherein at least portion of the polysilicon protection line is formed over the grounded doped region. See figure 3.

Claim Rejections - 35 U.S.C. § 103

- 8. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 9. Claim(s) 4 is/are rejected under 35 U.S.C. 103 (a) as being unpatentable over U.S. Patent No. 5,497,345 to Cappelletti, in view of the following remarks.

Regarding claim 4, Cappelletti discloses the device comprising all claimed limitations, except for the trapping layer including a silicon oxide/silicon nitride/silicon oxide (ONO) composite layer. However, it would have been obvious at the time the invention was made to a person having ordinary skill in the art to modify the invention of Cappelletti so that it would have an ONO trapping layer, because it is well known in the art that a charge trapping layer could be made by an ONO layer in order to obtain

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separately chargeable areas in the same trapping layer (for more information, see U.S.

Patent No. 6,583,007 to Eitan, column 4, lines 31-43).

Conclusion

10. A shortened statutory period for response to this action is set to expire 3 (three) months and 0 (zero) day from the day of this letter. Failure to respond within the period for response will cause the application to become abandoned (see M.P.E.P 710.02(b)).

11. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dao H. Nguyen whose telephone number is (571)272-1791. The examiner can normally be reached on Monday-Friday, 9:00 AM – 6:00 PM. If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached on (571)272-1787. The fax numbers for all communication(s) is 703-872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

David Nelms
Supervisory Patent Examiner
Technology Center 2800

Dao H. Nguyen Art Unit 2818 March 18, 2004